

## ■ Features

- N-Channel

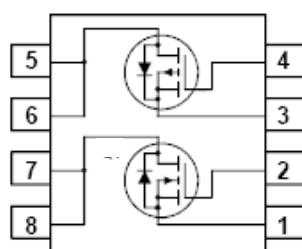
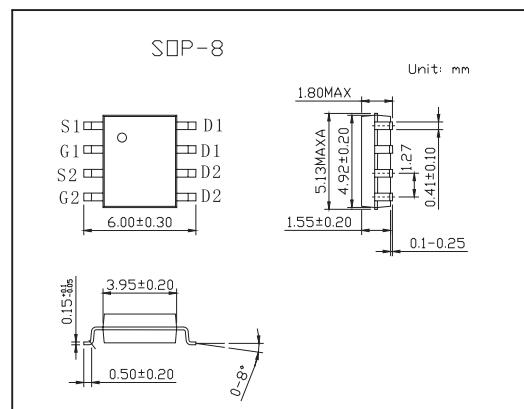
7.0 A, 30 V   R<sub>DSON</sub> = 0.028 Ω @ V<sub>GS</sub> = 10 V  
 R<sub>DSON</sub> = 0.040 Ω @ V<sub>GS</sub> = 4.5V

- P-Channel

-5 A, -30 V   R<sub>DSON</sub> = 0.052 Ω @ V<sub>GS</sub> = -10 V  
 R<sub>DSON</sub> = 0.080 Ω @ V<sub>GS</sub> = -4.5V

- Fast switching speed

- High power and handling capability in a widely used surface mount package



## ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	N-Channel	P- Channel	Unit
Drain to Source Voltage	V <sub>DSS</sub>	30	30	V
Gate to Source Voltage	V <sub>GS</sub>	±20	±20	V
Drain Current Continuous (Note 1a)	I <sub>D</sub>	7	-5	A
Drain Current Pulsed		20	-20	A
Power Dissipation for Single Operation	P <sub>D</sub>	2		W
Power Dissipation for Single Operation (Note 1a)	P <sub>D</sub>	1.6		W
(Note 1b)		1		
(Note 1c)		0.9		
Operating and Storage Temperature	T <sub>J</sub> , T <sub>STG</sub>	-55 to 150		°C
Thermal Resistance Junction to Ambient (Note 1a)	R <sub>θJA</sub>	78		°C/W
Thermal Resistance Junction to Case (Note 1)	R <sub>θJC</sub>	40		°C/W

**KDS8958**

## ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit	
Drain-Source Breakdown Voltage	Bvdss	Vgs = 0 V, Id = 250 μ A	N-Ch	30		V	
		Vgs = 0 V, Id = -250 μ A	P-Ch	-30			
Breakdown Voltage Temperature Coefficient	$\Delta B_{Vdss}$ $\Delta T_J$	Id = 250 μ A, Referenced to 25°C	N-Ch		25	mV/°C	
		Id = -250 μ A, Referenced to 25°C	P-Ch		-22		
Zero Gate Voltage Drain Current	Ibss	Vds = 24V, Vgs = 0 V	N-Ch		1	μ A	
		Vds = -24 V, Vgs = 0 V	P-Ch		-1		
Gate-Body Leakage	Igss	Vgs = ±20V, Vds = 0 V	N-Ch		±100	nA	
		Vgs = ±20 V, Vds = 0 V	P-Ch		±100		
Gate Threshold Voltage	Vgs(th)	Vds = Vgs, Id = 250 μ A	N-Ch	1	1.6	V	
		Vds = Vgs, Id = -250 μ A	P-Ch	-1	-1.7		
Gate Threshold Voltage Temperature Coefficient	$\Delta V_{gs(th)}$ $\Delta T_J$	Id = 250 μ A, Referenced to 25°C	N-Ch		-4.3	mV/°C	
		Id = -250 μ A, Referenced to 25°C	P-Ch		4		
Static Drain-Source On-Resistance	Rds(on)	Vgs = 10 V, Id = 7A	N-Ch		21	mΩ	
		Vgs = 10 V, Id = 7 A, TJ = 125°C			32		
		Vgs = 4.5 V, Id = 6 A			27		
Static Drain-Source On-Resistance	Rds(on)	Vgs = -10 V, Id = -5 A	P-Ch		41		
		Vgs = -10 V, Id = -5 A, TJ = 125°C			58		
		Vgs = -4.5 V, Id = -4A			58		
On-State Drain Current	Id(on)	Vgs = 10 V, Vds = 5V	N-Ch	20		A	
		Vgs = -10 V, Vds = -5V		-20			
Forward Transconductance	gfs	Vds = 5V, Id = 7A	N-Ch		19	S	
		Vds = -5V, Id = -5A			11		
Input Capacitance	Ciss	N-Channel Vds = 10 V, Vgs = 0 V, f = 1.0 MHz	N-Ch		789	pF	
					690		
Output Capacitance	Coss		N-Ch		173		
					306		
Reverse Transfer Capacitance	Crss	P-Channel Vds = -10 V, Vgs = 0 V, f = 1.0 MHz	N-Ch		66	pF	
					77		
Turn-On Delay Time	td(on)	N-Channel Vdd = 10 V, Id = 1 A, Vgs = 10 V, Rgen = 6 Ω (Note 2)	N-Ch		6	ns	
					6.7		
Turn-On Rise Time	tr		N-Ch		10	ns	
					9.7		
Turn-Off Delay Time	td(off)	P-Channel Vdd = -10 V, Id = -1 A, Vgs = -10 V, Rgen = 6 Ω (Note 2)	N-Ch		18	ns	
					19.8		
Turn-Off Fall Time	tf		N-Ch		5	ns	
					12.3		
Total Gate Charge	Qg	N-Channel Vds = 15V, Id = 7A, Vgs = 10V (Note 2)	N-Ch		16	nC	
					14		
Gate-Source Charge	Qgs		N-Ch		2.5	nC	
					2.2		
Gate-Drain Charge	Qgd	P-Channel Vds = -15V, Id = -5A, Vgs = -10V (Note 2)	N-Ch		2.1	nC	
					1.9		

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Parameter	Symbol	Testconditons		Min	Typ	Max	Unit
Maximum Continuous Drain-Source Diode Forward Current	Is		N-Ch P-Ch			1.3	A
						-1.3	
Drain-Source Diode Forward Voltage	Vsd	Vgs = 0 V, Is = 1.3A (Not 2)	N-Ch P-Ch		0.74	1.2	V
		Vgs = 0 V, Is = -1.3A (Not 2)			-0.76	-1.2	

**Notes:**

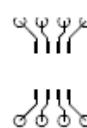
1.  $R_{eJA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{eJC}$  is guaranteed by design while  $R_{eCA}$  is determined by the user's board design.



a) 78°/W when mounted on a 0.5 in<sup>2</sup> pad of 2 oz copper



b) 125°/W when mounted on a .02 in<sup>2</sup> pad of 2 oz copper



c) 135°/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300μs, Duty Cycle < 2.0%